Octal D-type flip-flop; positive edge-trigger; 3-state Rev. 1 — 2 August 2012 Produ

Product data sheet

1. General description

The 74HC574-Q100; 74HCT574-Q100 is a high-speed Si-gate CMOS device and is pin compatible with Low-power Schottky TTL. It is specified in compliance with JEDEC standard no. 7A.

The 74HC574-Q100; 74HCT574-Q100 are octal D-type flip-flops featuring separate D-type inputs for each flip-flop and 3-state outputs for bus-oriented applications. A clock (CP) and an output enable (\overline{OE}) input are common to all flip-flops. The 8 flip-flops store the state of their individual D-inputs that meet the set-up and hold times requirements on the LOW-to-HIGH CP transition. When \overline{OE} is LOW the contents of the 8 flip-flops are available at the outputs. When \overline{OE} is HIGH, the outputs go to the high-impedance OFF-state. Operation of the \overline{OE} input does not affect the state of the flip-flops.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from –40 °C to +85 °C and from –40 °C to +125 °C
- 3-state non-inverting outputs for bus-oriented applications
- 8-bit positive, edge-triggered register
- Common 3-state output enable input
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Multiple package options

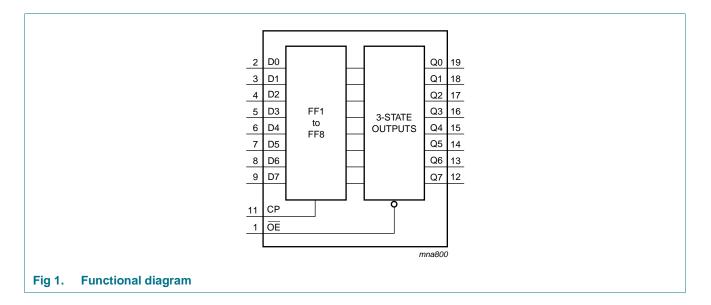


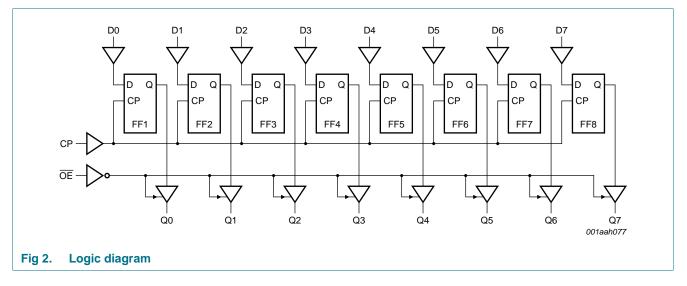
Octal D-type flip-flop; positive edge-trigger; 3-state

3. Ordering information

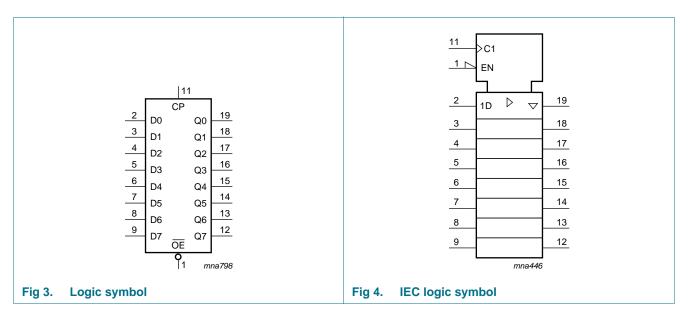
Table 1. Ordering information									
Type number	Package								
	Temperature range	Name	Description	Version					
74HC574D-Q100	–40 °C to +125 °C SO20		plastic small outline package; 20 leads;	SOT163-1					
74HCT574D-Q100			body width 7.5 mm						
74HC574PW-Q100	–40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads;	SOT360-1					
74HCT574PW-Q100			body width 4.4 mm						

4. Functional diagram



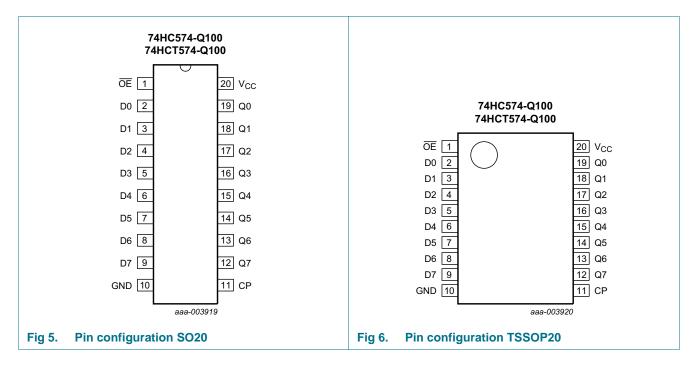


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5. Pinning information

5.1 Pinning



Octal D-type flip-flop; positive edge-trigger; 3-state

5.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
OE	1	3-state output enable input (active LOW)
D[0:7]	2, 3, 4, 5, 6, 7, 8, 9	data input
GND	10	ground (0 V)
CP	11	clock input (LOW-to-HIGH, edge triggered)
Q[0:7]	19, 18, 17, 16, 15, 14, 13, 12	3-state flip-flop output
V _{CC}	20	supply voltage

6. Functional description

Table 3.Function table

Operating mode	Input			Internal	Output
	OE	СР	Dn	flip-flop	Qn
Load and read register	L	\uparrow	I	L	L
	L	\uparrow	h	Н	Н
Load register and disable output	Н	\uparrow	I	L	Z
	Н	\uparrow	h	Н	Z

[1] H = HIGH voltage level;

h = HIGH voltage level one setup time prior to the HIGH-to-LOW CP transition;

L = LOW voltage level;

I = LOW voltage level one setup time prior to the HIGH-to-LOW CP transition;

Z = high-impedance OFF-state;

 \uparrow = LOW-to-HIGH clock transition.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_{\rm I}$ < –0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
Ι _{ΟΚ}	output clamping current	$V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
I _O	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$	-	±35	mA
I _{CC}	supply current		-	+70	mA
I _{GND}	ground current		-	-70	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation		<u>[1]</u> _	500	mW

[1] For SO20 packages: P_{tot} derates linearly with 8 mW/K above 70 °C.

For TSSOP20 packages: Ptot derates linearly with 5.5 mW/K above 60 °C.

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8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC	74HC574-Q100			74HCT574-Q100		
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 V$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC57	4-Q100									
VIH	HIGH-level	$V_{CC} = 2.0 V$	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	$V_{CC} = 4.5 V$	3.15	2.4	-	3.15	-	3.15	-	V
		$V_{CC} = 6.0 V$	4.2	3.2	-	4.2	-	4.2	-	V
V _{IL}	LOW-level	$V_{CC} = 2.0 V$	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	$V_{CC} = 4.5 V$	-	2.1	1.35	-	1.35	-	1.35	V
		$V_{CC} = 6.0 V$	-	2.8	1.8	-	1.8	-	1.8	V
V _{OH}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_0 = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_0 = -20 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	4.5	-	4.4	-	4.4	-	V
	$I_0 = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	5.9	-	5.9	-	V	
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	3.84	-	3.7	-	V
		I_{O} = -7.8 mA; V_{CC} = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	I_{O} = 20 $\mu A;$ V_{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I_O = 20 $\mu A; V_{CC}$ = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \ \mu\text{A}; \ V_{CC} = 6.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
		I_0 = 7.8 mA; V_{CC} = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
lı	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I _{OZ}	OFF-state output current		-	-	±0.5	-	±5.0	-	±10.0	μΑ

Octal D-type flip-flop; positive edge-trigger; 3-state

Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	-40 °C to	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Мах	-
lcc	supply current		-	-	8.0	-	80	-	160	μA
CI	input capacitance		-	3.5	-					pF
74HCT5	74-Q100									
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V _{он}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -6 mA	3.98	4.32	-	3.84	-	3.7	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = 20 μA	-	0	0.1	-	0.1	-	0.1	V
		l _O = 6.0 mA	-	0.16	0.26	-	0.33	-	0.4	V
I	input leakage current	$V_1 = V_{CC} \text{ or GND};$ $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μA
I _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 5.5$ V; $V_O = V_{CC}$ or GND per input pin; other inputs at V_{CC} or GND; $I_O = 0$ A	-	-	±0.5	-	±5.0	-	±10	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	8.0	-	80	-	160	μA
ΔI_{CC} additional supply current		$\label{eq:V_l} \begin{array}{l} V_l = V_{CC} - 2.1 \text{ V};\\ \text{other inputs at } V_{CC} \text{ or GND};\\ V_{CC} = 4.5 \text{ V to 5.5 V};\\ I_O = 0 \text{ A} \end{array}$								
		per input pin; Dn inputs	-	50	180	-	225	-	245	μΑ
		per input pin; OE input	-	125	450	-	563	-	613	μΑ
		per input pin; CP input	-	150	540	-	675	-	735	μΑ
CI	input capacitance		-	3.5	-					pF

Octal D-type flip-flop; positive edge-trigger; 3-state

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; for test circuit see Figure 10.

Symbol	Parameter	Conditions			25 °C		–40 °C	to +85 °C	–40 °C	to +125 °C	Unit
				Min	Тур	Max	Min	Max	Min	Max	
For type	74HC574-Q1	00									
t _{pd}	propagation	CP to Qn; see Figure 7	[1]								
	delay	$V_{CC} = 2.0 V$		-	47	150	-	190	-	225	ns
		$V_{CC} = 4.5 V$		-	17	30	-	35	-	45	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	14	-	-	-	-	-	ns
		$V_{CC} = 6.0 V$		-	14	26	-	33	-	38	ns
en	enable time	OE to Qn; see Figure 9	[2]								
		$V_{CC} = 2.0 V$		-	44	140	-	175	-	210	ns
		$V_{CC} = 4.5 V$		-	16	28	-	35	-	42	ns
		$V_{CC} = 6.0 V$		-	13	24	-	30	-	36	ns
t _{dis} disable time		OE to Qn; see Figure 9	[3]								
		$V_{CC} = 2.0 V$		-	39	125	-	155	-	190	ns
		$V_{CC} = 4.5 V$		-	14	25	-	31	-	38	ns
		$V_{CC} = 6.0 V$		-	11	21	-	26	-	32	ns
t	transition	Qn; see Figure 7	[4]								
	time	$V_{CC} = 2.0 V$		-	14	60	-	75	-	90	ns
		$V_{CC} = 4.5 V$		-	5	12	-	15	-	18	ns
		$V_{CC} = 6.0 V$		-	4	10	-	13	-	15	ns
W	pulse width	CP HIGH or LOW; see <u>Figure 8</u>									
		$V_{CC} = 2.0 V$		80	14	-	100	-	120	-	ns
		$V_{CC} = 4.5 V$		16	5	-	20	-	24	-	ns
		$V_{CC} = 6.0 V$		14	4	-	17	-	20	-	ns
su	set-up time	Dn to CP; see Figure 8									
		$V_{CC} = 2.0 V$		60	6	-	75	-	90	-	ns
		$V_{CC} = 4.5 V$		12	2	-	15	-	18	-	ns
		$V_{CC} = 6.0 V$		10	2	-	13	-	15	-	ns
h	hold time	Dn to CP; see Figure 8									
		$V_{CC} = 2.0 V$		5	0	-	5	-	5	-	ns
		$V_{CC} = 4.5 V$		5	0	-	5	-	5	-	ns
		$V_{CC} = 6.0 V$		5	0	-	5	-	5	-	ns
max	maximum	CP; see Figure 7									
	frequency	$V_{CC} = 2.0 V$		6.0	37	-	4.8	-	4.0	-	MH
		$V_{CC} = 4.5 V$		30	112	-	24	-	20	-	MH
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	123	-	-	-	-	-	MH
		$V_{CC} = 6.0 V$		35	133	-	28	-	24	-	MH

Octal D-type flip-flop; positive edge-trigger; 3-state

Symbol	Parameter	Conditions			25 °C		−40 °C	to +85 °C	–40 °C 1	to +125 °C	Unit
				Min	Тур	Max	Min	Max	Min	Max	
C _{PD}	power dissipation capacitance	C_L = 50 pF; f = 1 MHz; V _I = GND to V _{CC}	<u>[5]</u>	-	22	-	-	-	-	-	pF
For type	74HCT574-Q	100									
t _{pd}	propagation	CP to Qn; see Figure 7	[1]								
	delay	$V_{CC} = 4.5 V$		-	18	33	-	41	-	50	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	15	-	-	-	-	-	ns
t _{en}	enable time	OE to Qn; see Figure 9	[2]								
		$V_{CC} = 4.5 V$		-	19	33	-	41	-	50	ns
t _{dis}	disable time	OE to Qn; see Figure 9	[3]								
		$V_{CC} = 4.5 V$		-	16	28	-	35	-	42	ns
t _t	transition	Qn; see Figure 7	[4]								
	time	$V_{CC} = 4.5 V$		-	5	12	-	15	-	18	ns
t _W	pulse width	CP HIGH or LOW; see Figure 8									
		$V_{CC} = 4.5 V$		16	7	-	20	-	24	-	ns
t _{su}	set-up time	Dn to CP; see Figure 8									
		$V_{CC} = 4.5 V$		12	3	-	15	-	18	-	ns
t _h	hold time	Dn to CP; see Figure 8									
		$V_{CC} = 4.5 V$		5	-1	-	5	-	5	-	ns
f _{max}	maximum	CP; see Figure 7									
	frequency	$V_{CC} = 4.5 V$		30	69	-	24	-	20	-	MHz
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	76	-	-	-	-	-	MHz
C _{PD}	power dissipation capacitance	C_L = 50 pF; f = 1 MHz; V _I = GND to V _{CC}	<u>[5]</u>	-	25	-	-	-	-	-	pF

Table 7. Dynamic characteristics ... continued

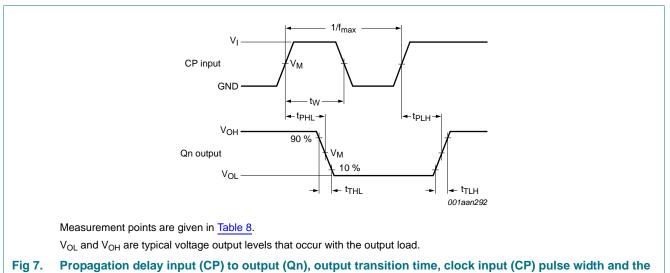
[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

- [2] t_{en} is the same as t_{PZH} and t_{PZL} .
- [3] t_{dis} is the same as t_{PLZ} and t_{PHZ} .
- [4] t_t is the same as t_{THL} and t_{TLH} .
- [5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW). P_{D} = $C_{PD} \times V_{CC}{}^{2} \times f_{i} \times N$ + $\Sigma (C_{L} \times V_{CC}{}^{2} \times f_{o})$ where: f_i = input frequency in MHz; $f_o = output frequency in MHz;$ C_L = output load capacitance in pF; V_{CC} = supply voltage in V; N = number of inputs switching;

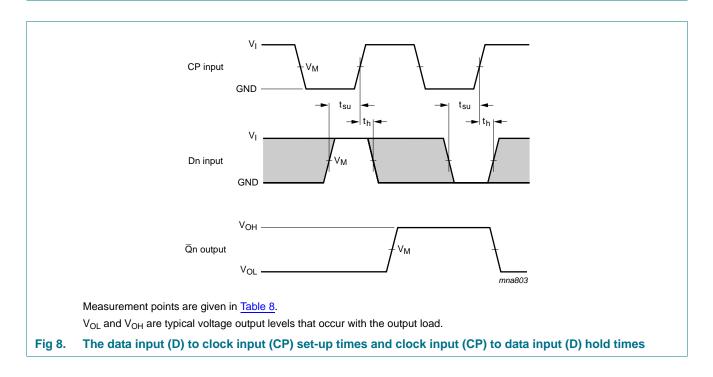
 $\Sigma(C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$

Octal D-type flip-flop; positive edge-trigger; 3-state

11. Waveforms







Octal D-type flip-flop; positive edge-trigger; 3-state

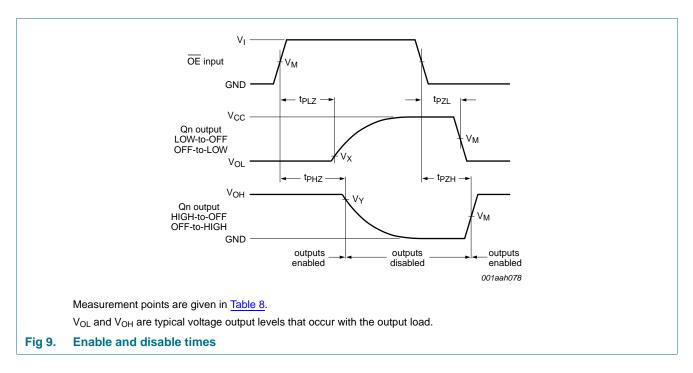


Table 8.Measurement points

Туре	Input	Output	Output					
	V _M	V _M	V _X	V _Y				
74HC574-Q100	0.5V _{CC}	0.5V _{CC}	0.1V _{CC}	0.9V _{CC}				
74HCT574-Q100	1.3 V	1.3 V	0.1V _{CC}	0.9V _{CC}				

Octal D-type flip-flop; positive edge-trigger; 3-state

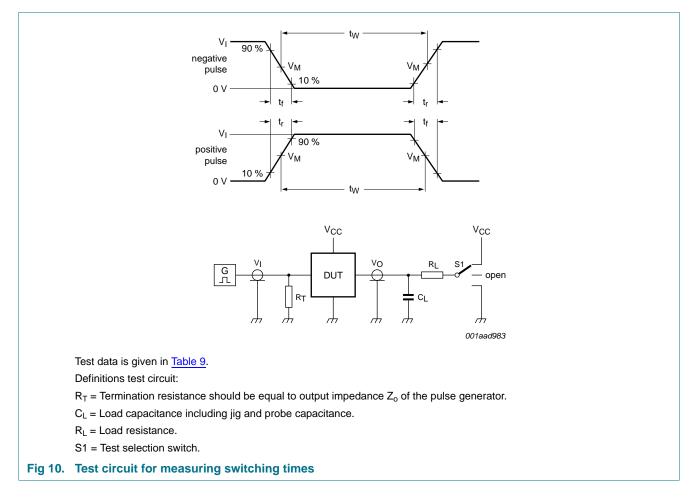


Table 9. Test data

Туре	Input		Load		S1 position		
	VI	t _r , t _f	CL	RL	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
74HC574-Q100	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}
74HCT574-Q100	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}

Octal D-type flip-flop; positive edge-trigger; 3-state

12. Package outline

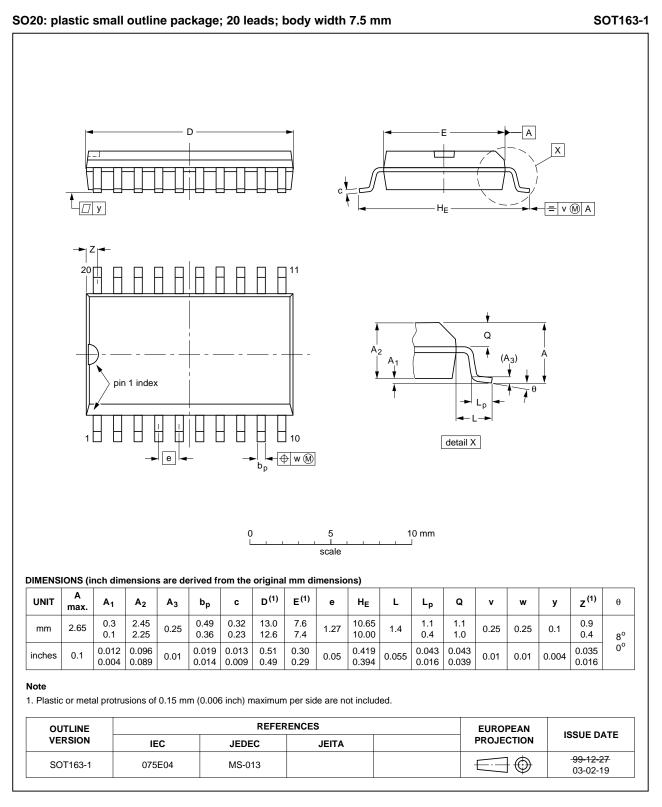


Fig 11. Package outline SOT163-1 (SO20)

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Octal D-type flip-flop; positive edge-trigger; 3-state

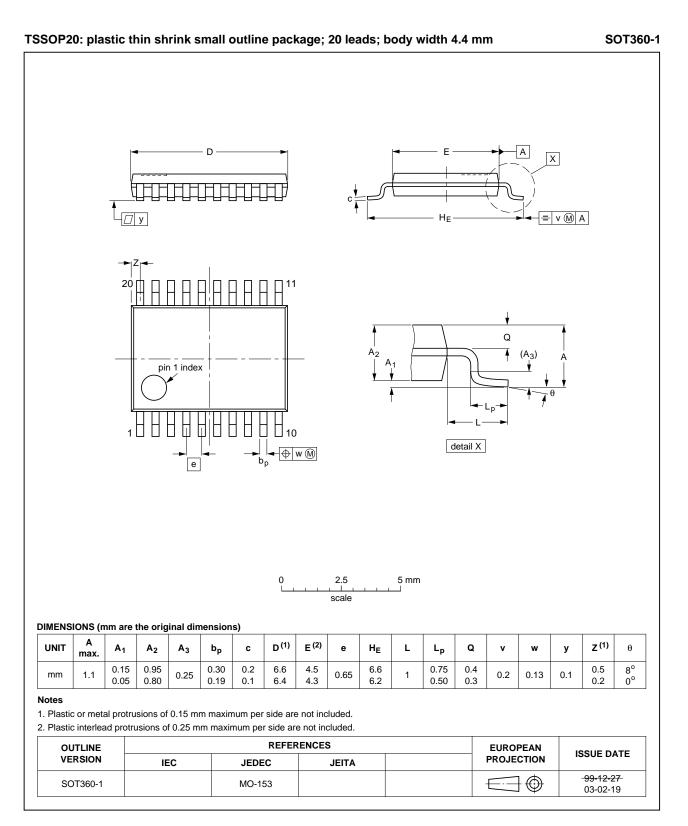


Fig 12. Package outline SOT360-1 (TSSOP20)

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Octal D-type flip-flop; positive edge-trigger; 3-state

13. Abbreviations

Table 10.	Abbreviations
Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic
MIL	Military

14. Revision history

Table 11. Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes	
74HC_HCT574_Q100 v.1	20120802	Product data sheet	-	-	

Octal D-type flip-flop; positive edge-trigger; 3-state

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Octal D-type flip-flop; positive edge-trigger; 3-state

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NXP Semiconductors

74HC574-Q100; 74HCT574-Q100

Octal D-type flip-flop; positive edge-trigger; 3-state

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Date of release: 2 August 2012 Document identifier: 74HC_HCT574_Q100